Package Options Include Plastic Small-Outline (D) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

description

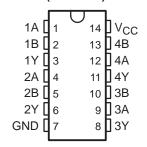
These devices contain four independent 2-input positive-NAND buffers. They perform the Boolean functions $Y = \overline{A} \cdot \overline{B}$ or $Y = \overline{A} + \overline{B}$ in positive logic.

The SN54ALS37A is characterized for operation over the full military temperature range of -55° C to 125°C. The SN74ALS37A is characterized for operation from 0°C to 70°C.

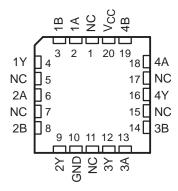
FUNCTION TABLE (each gate)

INP	UTS	OUTPUT
Α	В	Y
Н	Н	L
L	Χ	Н
Х	L	Н

SN54ALS37A . . . J PACKAGE SN74ALS37A . . . D OR N PACKAGE (TOP VIEW)

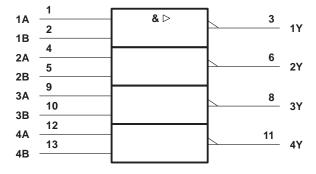


SN54ALS37A . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

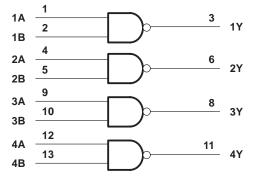
logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for the D, J, and N packages.

logic diagram (positive logic)





SN54ALS37A, SN74ALS37A QUADRUPLE 2-INPUT POSITIVE-NAND BUFFERS

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{CC}		7 V
Input voltage, V _I		7 V
Operating free-air temperature range, TA: S	SN54ALS37A	-55°C to 125°C
	SN74ALS37A	0°C to 70°C
Storage temperature range		-65°C to 150°C

recommended operating conditions

		SN54ALS37A			SN74ALS37A			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Vcc	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
VIL	Low-level input voltage			0.7			0.8	V
ЮН	High-level output current			-1			-2.6	mA
loL	Low-level output current	12				24	mA	
TA	Operating free-air temperature	-55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		SN	SN54ALS37A			SN74ALS37A			
			MIN	TYP [‡]	MAX	MIN	TYP‡	MAX	UNIT	
VIK	V _{CC} = 4.5 V,	I _I = -18 mA			-1.5			-1.5	V	
	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V},$	$I_{OH} = -0.4 \text{ mA}$	Vcc	<u>,</u> –2		VCC	; - 2			
VOH	V _{CC} = 4.5 V	I _{OH} = −1 mA	2.4	3.3					V	
		$I_{OH} = -2.6 \text{ mA}$				2.4	3.3			
V _{OL}	V 45.V	I _{OL} = 12 mA		0.25	0.4		0.25	0.4	V	
	V _{CC} = 4.5 V	I _{OL} = 24 mA					0.35	0.5		
I _I	$V_{CC} = 5.5 \text{ V},$	V _I = 7 V			0.1			0.1	mA	
lін	$V_{CC} = 5.5 \text{ V},$	V _I = 2.7 V			20			20	μΑ	
I _{IL}	V _{CC} = 5.5 V,	V _I = 0.4 V			-0.1			-0.1	mA	
ΙΟ [§]	V _{CC} = 5.5 V,	V _O = 2.25 V	-20		-112	-30		-112	mA	
Іссн	V _{CC} = 5.5 V,	V _I = 0		0.86	1.6		0.86	1.6	mA	
ICCL	V _{CC} = 5.5 V,	V _I = 4.5 V		4.8	7.8		4.8	7.8	mA	

[‡] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.



[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

[§] The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.

SN54ALS37A, SN74ALS37A QUADRUPLE 2-INPUT POSITIVE-NAND BUFFERS

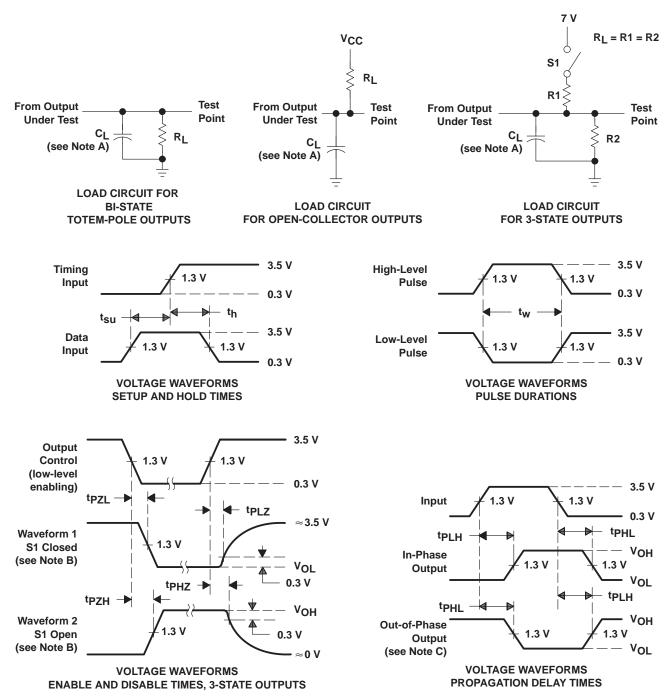
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switching characteristics (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _C C _L R _L T _A	UNIT			
			SN54ALS37A		SN74ALS37A		
			MIN	MAX	MIN	MAX	
^t PLH	A or B	V	2	17	2	8	ns
^t PHL	AOID	ſ	2	9	2	7	115

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

PARAMETER MEASUREMENT INFORMATION SERIES 54ALS/74ALS AND 54AS/74AS DEVICES



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. When measuring propagation delay items of 3-state outputs, switch S1 is open.
- D. All input pulses have the following characteristics: PRR \leq 1 MHz, $t_f = t_f = 2$ ns, duty cycle = 50%.
- E. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuits and Voltage Waveforms



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